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HAT1048R

Silicon P Channel Power MOS FET Power Switching



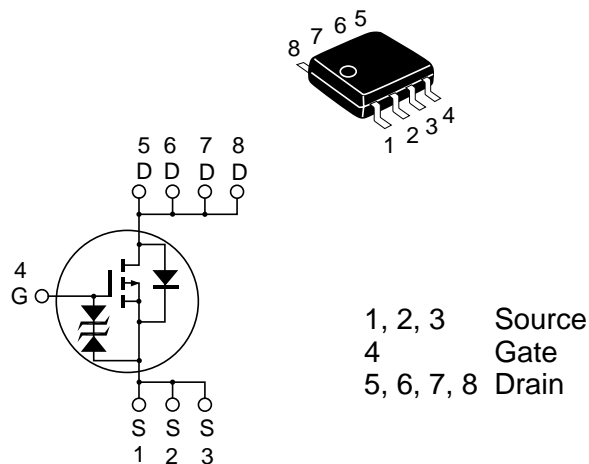
ADE-208-1223A (Z)
 2nd. Edition
 Jan. 2001

Features

- Capable of -4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
 $R_{DS(on)} = 6.0 \text{ m}\Omega \text{ typ}$ (at $V_{GS} = -10\text{V}$)

Outline

SOP-8



HAT1048R

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	-30	V
Gate to source voltage	V_{GSS}	± 20	V
Drain current	I_D	-16	A
Drain peak current	$I_{D(pulse)}$ ^{Note1}	-128	A
Body-drain diode reverse drain current	I_{DR}	-16	A
Channel dissipation	P_{ch} ^{Note2}	2.5	W
Channel to Ambient Thermal Impedance	θ_{ch-a} ^{Note2}	50	°C/W
Channel temperature	T_{ch}	150	°C
Storage temperature	T_{stg}	- 55 to + 150	°C

Note: 1. $PW \leq 10 \mu s$, duty cycle $\leq 1\%$

2. When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), $PW \leq 10s$

Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-30	—	—	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	± 20	—	—	V	$I_G = \pm 100 \mu\text{A}, V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	-1	μA	$V_{DS} = -30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0	—	-2.5	V	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	(6.0)	(7.0)	$\text{m}\Omega$	$I_D = -8 \text{ A}, V_{GS} = -10 \text{ V}$ ^{Note3}
	$R_{DS(on)}$	—	(9.5)	(13.5)	$\text{m}\Omega$	$I_D = -8 \text{ A}, V_{GS} = -4.5 \text{ V}$ ^{Note3}
Forward transfer admittance	$ y_{fs} $	(18)	(30)	—	S	$I_D = -8 \text{ A}, V_{DS} = -10 \text{ V}$ ^{Note3}
Input capacitance	Ciss	—	(5700)	—	pF	$V_{DS} = -10 \text{ V}$
Output capacitance	Coss	—	(1250)	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	—	(710)	—	pF	$f = 1 \text{ MHz}$
Total gate charge	Qg	—	(105)	—	nc	$V_{DD} = -10 \text{ V}$
Gate to source charge	Qgs	—	(14)	—	nc	$V_{GS} = -10 \text{ V}$
Gate to drain charge	Qgd	—	(20)	—	nc	$I_D = -16 \text{ A}$
Turn-on delay time	$t_{d(on)}$	—	(25)	—	ns	$V_{GS} = -10 \text{ V}, I_D = -8 \text{ A}$
Rise time	t_r	—	(45)	—	ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	(140)	—	ns	$R_L = 1.25 \Omega$
Fall time	t_f	—	(55)	—	ns	$R_g = 4.7 \Omega$
Body–drain diode forward voltage	V_{DF}	—	(-0.85)	(-1.10)	V	$I_F = -16 \text{ A}, V_{GS} = 0$ ^{Note3}
Body–drain diode reverse recovery time	t_{rr}	—	(50)	—	ns	$I_F = -16 \text{ A}, V_{GS} = 0 \text{ diF/ dt} = 50 \text{ A/}\mu\text{s}$

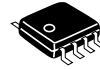
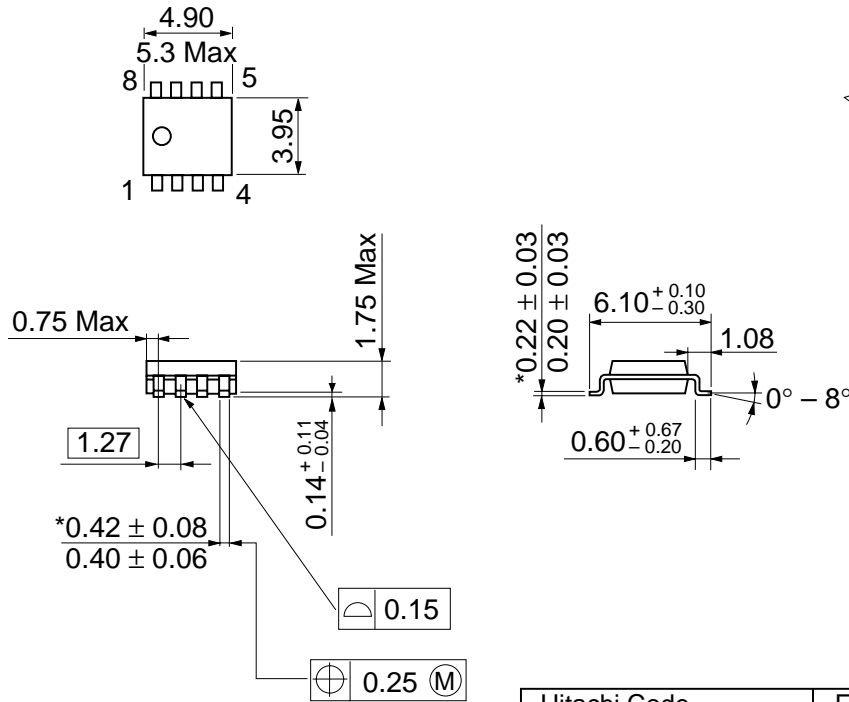
Note: 3. Pulse test

HAT1048R

Package Dimensions

As of January, 2001

Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-8DA
JEDEC	Conforms
EIAJ	—
Mass (reference value)	0.085 g

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